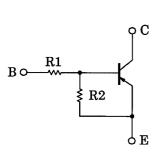
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

## RN2701,RN2702,RN2703,RN2704,RN2705,RN2706

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in USV (ultra super mini type with 5 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1701~1706

### **Equivalent Circuit and Bias Resistor Values**



Type No.	R1 (kΩ)	R2 (kΩ)		
RN2701	4.7	4.7		
RN2702	10	10		
RN2703	22	22		
RN2704	47	47		
RN2705	2.2	47		
RN2706	4.7	47		

1. BASE 1 (B1)
2. EMITTER (E)
3. BASE 2 (B2)
4. COLLECTOR 1 (C1)

JEDEC —

EIAJ ——

Weight: 6.2mg

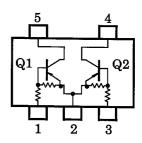
**TOSHIBA** 

### **Equivalent Circuit (Top View)**

## Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Rating	Unit
Collector-base voltage	RN2701~2706	$V_{CBO}$	-50	V
Collector-emitter voltage	1(102701-2700	$V_{CEO}$	-50	<b>V</b>
	RN2701~2704		-10	
	RN2705, 2706		-5	
Collector current		IC	-100	mA
Collector power dissipation		P <sub>C</sub> *	200	mW
Junction temperature		Tj	150	°C
Storage temperature range		T <sub>stg</sub>	-55~150	°C

<sup>\*:</sup> Total rating



2-2L1A

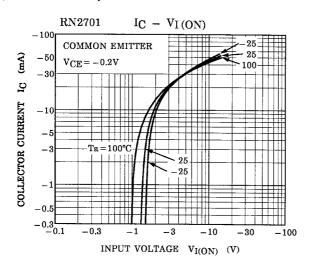


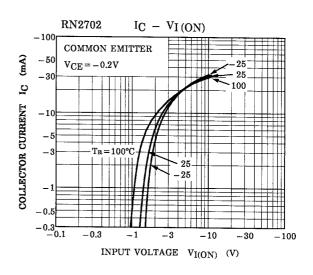
# Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

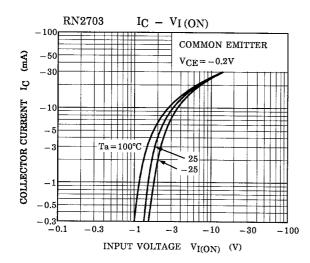
Characteri	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	DN2701-2706	I <sub>CBO</sub>	_	V <sub>CB</sub> = -50V, I <sub>E</sub> = 0	_	_	-100	nA
	RN2701~2706	I <sub>CEO</sub>	_	V <sub>CE</sub> = -50V, I <sub>B</sub> = 0	_	_	-500	
	RN2701	- I <sub>EBO</sub>	_	V <sub>EB</sub> = -10V, I <sub>C</sub> = 0	-0.82	_	-1.52	mA
	RN2702		_		-0.38	_	-0.71	
Facilities and off assessed	RN2703		_		-0.17	_	-0.33	
Emitter cut-off current	RN2704		_		-0.082	_	-0.15	
	RN2705		_		-0.078	_	-0.145	
	RN2706		_	$V_{EB} = -5V, I_{C} = 0$	-0.074	_	-0.138	
	RN2701		<b>1</b> –		30	_	_	
	RN2702		_		50	_	_	
	RN2703		_	V <sub>CE</sub> = -5V	70	_	_	
DC current gain	RN2704	h <sub>FE</sub>	_	I <sub>C</sub> = -10mA	80	_	_	
	RN2705		_		80	_	_	
	RN2706		_		80	_	_	
Collector-emitter saturation voltage	RN2701~2706	V <sub>CE (sat)</sub>	_	$I_{C} = -5mA$ $I_{B} = -0.25mA$	_	-0.1	-0.3	٧
Input voltage (ON)	RN2701	V <sub>I</sub> (ON)	<b>1</b> –	V <sub>CE</sub> = -0.2V I <sub>C</sub> = -5mA	-1.1	_	-2.0	V
	RN2702		_		-1.2	_	-2.4	
	RN2703		_		-1.3	_	-3.0	
	RN2704		_		-1.5	_	-5.0	
	RN2705		_		-0.6	_	-1.1	
	RN2706		_		-0.7	_	-1.3	
Innut valtage (OFF)	RN2701~2704	V <sub>I (OFF)</sub>	_	V <sub>CE</sub> = -5V, I <sub>C</sub> = -0.1mA	-1.0	_	-1.5	V
Input voltage (OFF)	RN2705, 2706		_		-0.5	_	-0.8	
Translation frequency	RN2701~2706	f <sub>T</sub>	_	V <sub>CE</sub> = -10V, I <sub>C</sub> = -5mA	_	200	_	MHz
Collector output capacitance	RN2701~2706	C <sub>ob</sub>	_	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0 f = 1MHz	_	3	6	pF
Input resistor	RN2701	R1	_		3.29	4.7	6.11	
	RN2702		_		7	10	13	
	RN2703		_		15.4	22	28.6	
	RN2704		_	_	32.9	47	61.1	kΩ
	RN2705		_		1.54	2.2	2.86	
	RN2706		_		3.29	4.7	6.11	
Resistor ratio	RN2701~2704	R1/R2	<u> </u>		0.9	1.0	1.1	$\top$
	RN2705		_	_	0.0421	0.0468	0.0515	_
	RN2706		_		0.09	0.1	0.11	

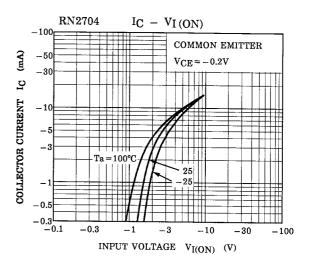
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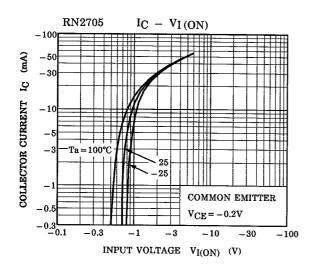
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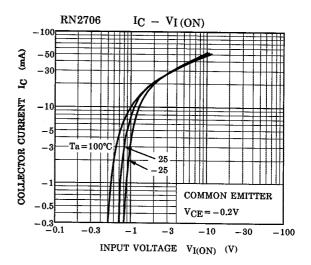






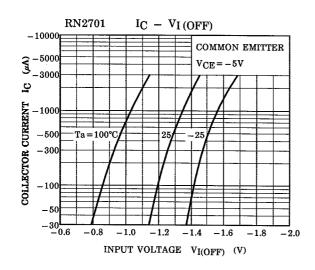


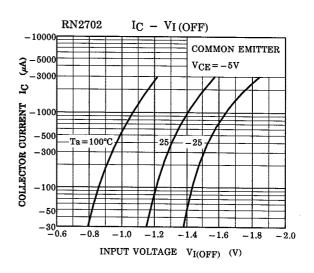


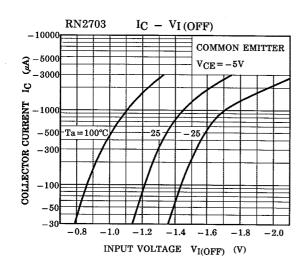


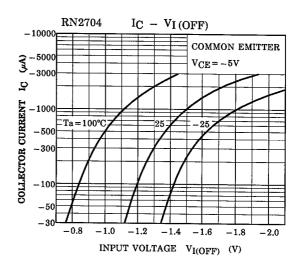
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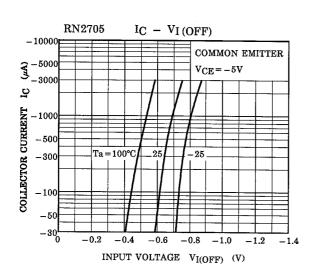
### (Q1, Q2 Common)

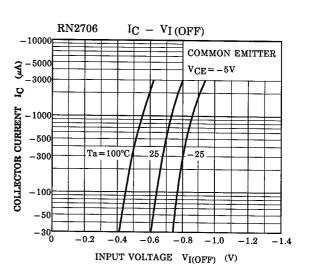




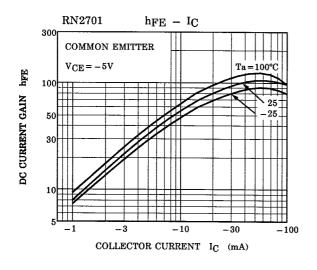


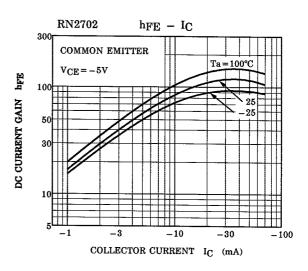


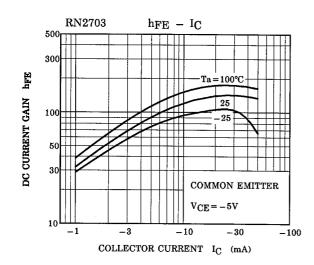


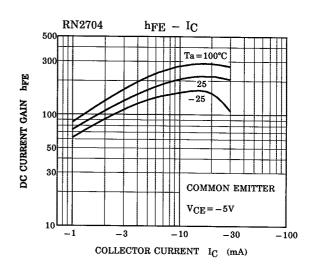


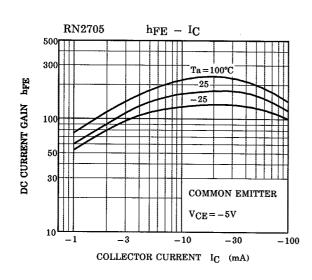
### (Q1, Q2 Common)

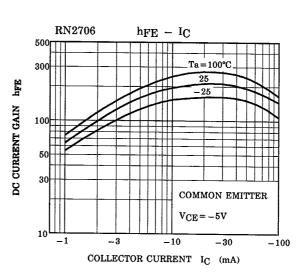












5

Type Name	Marking
RN2701	Type Name YA
RN2702	Type Name Y B
RN2703	Type Name Y C
RN2704	Type Name Y D
RN2705	Type Name YE
RN2706	Type Name Y F

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000707EAA

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